

MOS FIELD EFFECT TRANSISTOR **2SK4145**

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK4145 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

Low on-state resistance

 $R_{DS(on)} = 10 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, \text{ ID} = 42 \text{ A})$

• Low input capacitance

Ciss = 5300 pF TYP.

ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
2SK4145-S19-AY Note	Pure Sn (Tin)	Tube 50 p/tube	TO-220 typ. 1.9 g

Note Pb-free (This product does not contain Pb in the external electrode).

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGs = 0 V)	VDSS	60	V
Gate to Source Voltage (VDs = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±84	А
Drain Current (pulse) ^{Note1}	D(pulse)	±215	А
Total Power Dissipation (Tc = 25°C)	P _{T1}	84	W
Total Power Dissipation (T _A = 25°C)	Pt2	1.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	32	А
Single Avalanche Energy Note2	Eas	102	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 30 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V, L = 100 μ H

THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	1.49	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

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The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 60 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	lgss	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	2.0	3.0	4.0	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 30 A	16	31		S
Drain to Source On-state Resistance Note	RDS(on)	Vgs = 10 V, Id = 42 A		7	10	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V,		5300		pF
Output Capacitance	Coss	V _{GS} = 0 V,		540		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		330		рF
Turn-on Delay Time	td(on)	V _{DD} = 30 V, I _D = 42 A,		25		ns
Rise Time	tr	V _{GS} = 10 V,		17		ns
Turn-off Delay Time	td(off)	R _G = 0 Ω		66		ns
Fall Time	tr			9		ns
Total Gate Charge	QG	V _{DD} = 48 V,		90		nC
Gate to Source Charge	QGS	V _{GS} = 10 V,		21		nC
Gate to Drain Charge	Qgd	I⊳ = 84 A		30		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	IF = 84 A, VGS = 0 V		1.0	1.5	V
Reverse Recovery Time	trr	IF = 84 A, VGS = 0 V,		43		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		62		nC

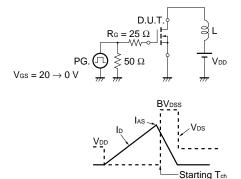
ELECTRICAL CHARACTERISTICS (TA = 25°C)

Note Pulsed

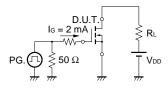
TEST CIRCUIT 1 AVALANCHE CAPABILITY

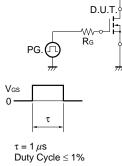
TEST CIRCUIT 2 SWITCHING TIME

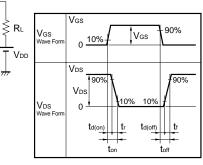
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TEST CIRCUIT 3 GATE CHARGE

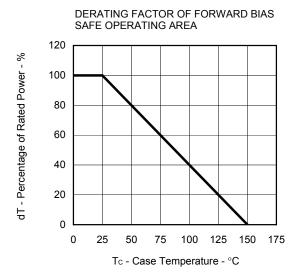


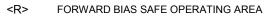


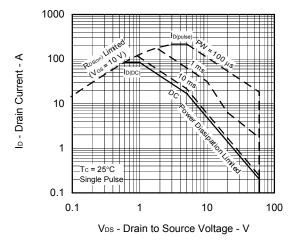


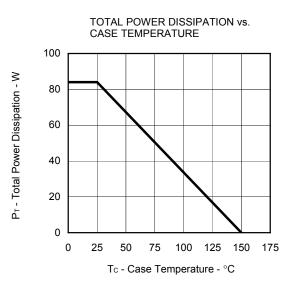
Data Sheet D18760EJ2V0DS

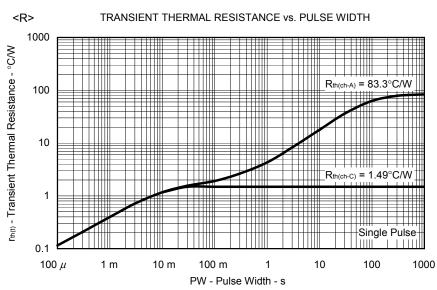
TYPICAL CHARACTERISTICS (TA = 25°C)



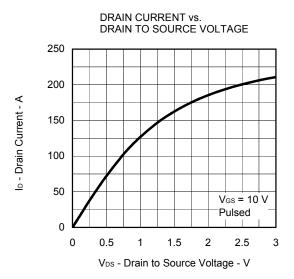




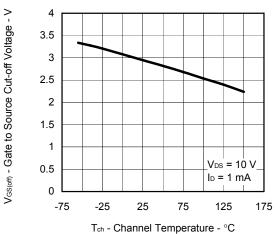


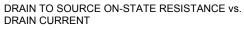


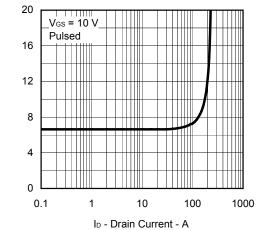
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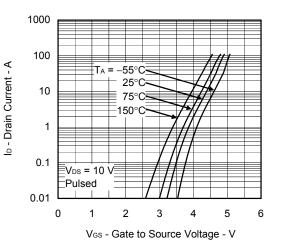




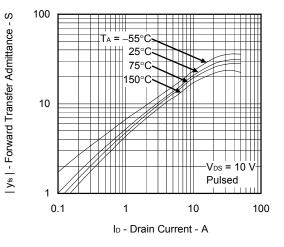




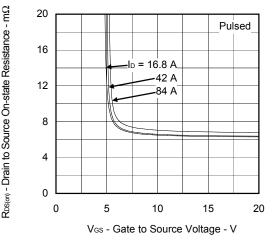
FORWARD TRANSFER CHARACTERISTICS



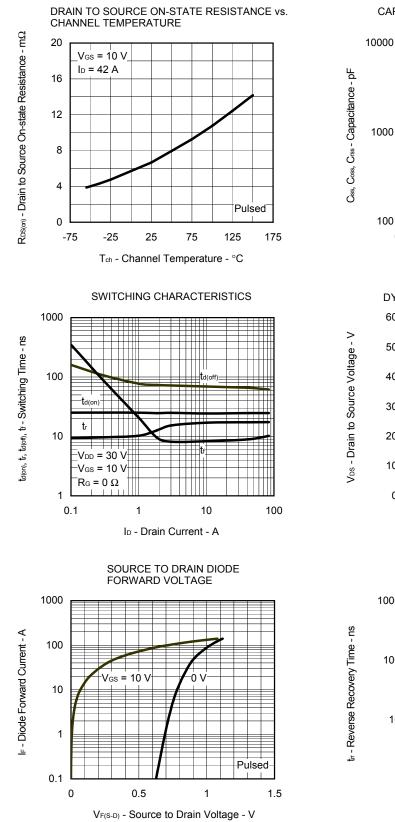
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



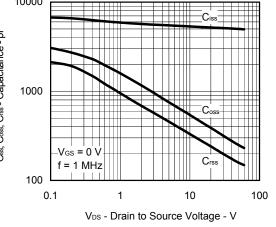
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



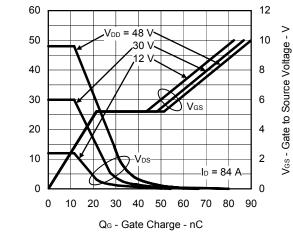
 $R_{DS(on)}$ - Drain to Source On-state Resistance - $m\Omega$



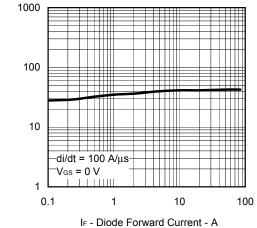
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



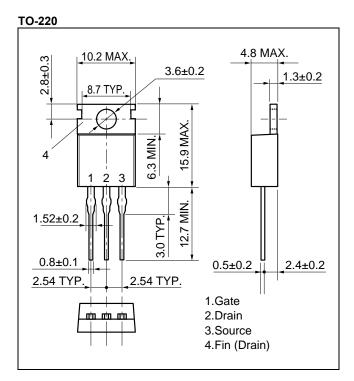
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



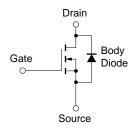
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



PACKAGE DRAWING (Unit: mm)



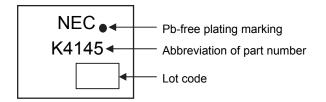
EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

MARKING INFORMATION

NEC



RECOMMENDED SOLDERING CONDITIONS

The 2SK4145 should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Wave soldering	Maximum temperature (Solder temperature): 260°C or below Time: 10 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	THDWS
Partial heating	Maximum temperature (Pin temperature): 350°C or below Time (per side of the device): 3 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	P350

Caution Do not use different soldering methods together (except for partial heating).

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